		D STATES PAT					
Applicant(s):	Brian A. Vaartstra		Gro	up Art Unit:		RECEIVE	
Serial No.:	09/865,612		Exa	miner:	D.M. C	Atur.	
Filed:	May 25, 2001			ket No.:	156.00	810402-7.	
Γitle:	METHODS, COMI ON SEMICONDUC	ay 25, 2001 Docket No.: 156.00870102, Confirmation No.: 4697 ETHODS, COMPLEXES, AND SYSTEMS FOR FORMING METAL-CONTAINING FOR SEMICONDUCTOR STRUCTURES					
Assistant Commis Washington, D.C.	ssioner for Patents 20231				7	-	
Ve are transmittir	ng the following doc	uments along with t	this Transmittal She	eet (which is s	ubmitte	ed in triplicate):	
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_ A check in A certified claimed use. Δ Other:	in the amount of \$_cd copy of a applied under 35 U.S.C. §11 Response (4 pgs.) ent No Additi	, for cation, Serial No 9. onal fee is required.	The fee has	been calculat			
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MUETING, RAASCH & GEBHARDT, P.A.

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PATENT TRADEMARK OFFICE

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CERTIFICATE UNDER 37 CFR §1.10:

"Express Mail" mailing label number: EL888272878US

Date of Deposit: March 6, 2002

I hereby certify that this paper or fee is being deposited with the United States Postal Service "Express Mail Post Office to Addressee" service under 37 CFR §1.10 on the date indicated above and is addressed to the Assistant Commissioner for Patents,

Name: Suc Dombroske

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PATENT 19 br. Docket No. 150.00810102

IN THE UNITED STATES PATERINAND TRADEMARK OFFICE

Applicant(s): Brian A. Vaartstra) Group Art Unit: 2823

Serial No.: 09/865,612) Examiner: D.M. Collins

Confirmation No.: 4697

Filed: May 25, 2001

For: METHODS, COMPLEXES, AND SYSTEMS FOR FORMING METAL-

CONTAINING FILMS ON SEMICONDUCTOR STRUCTURES

RESPONSE

Assistant Commissioner for Patents Washington D.C. 20231

Dear Sir:

The Office Action mailed 6 December 2001 has been received and reviewed. Applicant addresses the Office Action as follows.

Remarks

The Office Action mailed December 6, 2001, has been received and reviewed. No claims were amended, cancelled, or added. Claims 18-38 are pending. Reconsideration and withdrawal of the rejections are respectfully requested.

Double Patenting Rejection

Claims 18-38 were rejected under the judicially created doctrine of obviousness-type double patenting as being unpatentable over claims 1-34 of U.S. Patent No. 6,306,217. The Examiner asserted that although the conflicting claims were not identical, they were not patentably distinct from each other because the claims of the instant application show a chemical vapor deposition system. The Examiner asserted that U.S. Pat. No. 6,306,217 shows a chemical vapor deposition system comprising a deposition chamber having a semiconductor substrate and a vessel containing a precursor composition. As such, the Examiner asserted that it would have been obvious to one of ordinary skill in the art at the time the invention was made that using